

C E R T I F I C A T E



of Conformity Low Voltage Directive 2006/95/EC

Registration No.: AN 50282062 0001

Report No.: 15058173 014

Holder: **Chint Solar (Zhejiang) Co., Ltd.**
1335 Bin An Rd., Binjiang District
Hangzhou 310053
P.R. China

Product: PV-Module

Identification: With 5" mono c-Si cells:
CHSM5612M (FR)-xxx (xxx=155-210, in steps of 5, 72 cells)
CHSM5611M (FR)-xxx (xxx=145-195, in steps of 5, 66 cells)
CHSM5610M (FR)-xxx (xxx=130-180, in steps of 5, 60 cells)
CHSM5609M (FR)-xxx (xxx=115-160, in steps of 5, 54 cells)
CHSM5608M (FR)-xxx (xxx=105-140, in steps of 5, 48 cells)
See more module type designations in attachment 1.1

This certificate of conformity is based on an evaluation of a sample of the above mentioned product. Technical Report and documentation are at the Licence Holder's disposal. This is to certify that the tested sample is in conformity with all revision of Annex I of Council Directive 2006/95/EC, in its latest amended version, referred to as the Low Voltage Directive. This certificate does not imply assessment of the series-production of the product and does not permit the use of a TÜV Rheinland mark of conformity. The holder of the certificate is authorized to use this certificate in connection with the EC declaration of conformity according to Annex III of the Directive.



Certification Body

Date 07.05.2014

A handwritten signature in blue ink, appearing to read "G. Reimann".

Dipl.-Ing. (TU) G. Reimann

TÜV Rheinland LGA Products GmbH - Tillystraße 2 - 90431 Nürnberg

CE The CE marking may be used if all relevant and effective EC Directives are complied with. CE

TÜV Rheinland
LGA Products GmbH
Tillystraße 2, 90431 Nürnberg

Attachment to
Registration No.: AN 50282062 0001
Report No.: 15058173 014

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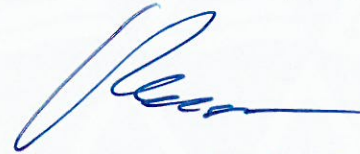
Scope:

With 5" mono c-Si cells:
CHSM5607M (FR)-xxx (xxx=090-125, in steps of 5, 42 cells)
CHSM5606M (FR)-xxx (xxx=075-105, in steps of 5, 36 cells)

With 6" mono c-Si cells:
CHSM6610M (FR)-xxx (xxx=210-275, in steps of 5, 60 cells)
CHSM6609M (FR)-xxx (xxx=185-245, in steps of 5, 54 cells)
CHSM6608M (FR)-xxx (xxx=170-220, in steps of 5, 48 cells)
CHSM6607M (FR)-xxx (xxx=155-195, in steps of 5, 42 cells)
CHSM6606M (FR)-xxx (xxx=130-165, in steps of 5, 36 cells)

With 6" poly c-Si cells:
CHSM6612P (FR)-xxx (xxx=245-320, in steps of 5, 72 cells)
CHSM6611P (FR)-xxx (xxx=245-290, in steps of 5, 66 cells)
CHSM6610P (FR)-xxx (xxx=200-265, in steps of 5, 60 cells)
CHSM6609P (FR)-xxx (xxx=180-240, in steps of 5, 54 cells)
CHSM6608P (FR)-xxx (xxx=155-210, in steps of 5, 48 cells)
CHSM6607P (FR)-xxx (xxx=135-185, in steps of 5, 42 cells)
CHSM6606P (FR)-xxx (xxx=120-160, in steps of 5, 36 cells)

Cologne, 07.05.2014



Dipl.-Ing. (TU) G. Reimann